## E ect of Structure on the Electronic D ensity of States

ofD oped Lanthanum Cuprate

M.R.Nomman

M aterials Science D ivision Argonne National Laboratory Argonne, IL 60439

G.J.M dM ullan

C avendish Laboratory M adingley Road C am bridge CB30HE, UK

D.L.Novikov and A.J.Freem an

Science and Technology Center for Superconductivity and Department of Physics and Astronom y Northwestern University Evanston, IL 60208

We present a series of detailed band calculations on the various structural phases of doped lanthanum cuprate: HTT, LTO, and LTT. The LTO distortion is shown to have little e ect on the electronic density of states (DOS). A to the pressure dependence of the superconducting transition tem perature indicates that only 2.5% of the DOS is a ected by the HTT! LTO transition. The LTT distortion also has little e ect on the DOS for the experimental value of the octahedral tilt angle. Larger tilt angles, though, lead to a dram atic change in the DOS.

PACS num bers: 71.25 P i, 74.70 V y

D oped lanthanum cuprate, La<sub>2 x</sub>M <sub>x</sub>C uO<sub>4</sub>, where M is typically Sr or Ba, is the prototype system for the class of copper oxide m aterials known as high tem perature superconductors. It exhibits a number of structural phases, each of which has di erent superconducting properties. The HTT (high tem perature body-centered tetragonal) phase occurs for low tem peratures only for x > 0.2, where superconductivity is suppressed. At lower tem peratures for x < 0.2, one nds the LTO (low tem perature face-centered orthorhom bic) phase, which is superconducting over a range of x values. Near x=0.125, the LTT (low tem perature primitive tetragonal) phase forms for the Ba system with suppressed superconductivity. A sm all dip in T<sub>c</sub> near x=0.115 is found in the Sr system, but no evidence for the LTT phase. M ore inform ation has now been gathered by hydrostatic pressure experiments<sup>1</sup>. For the range of x values where one has a superconducting LTO phase, the HTT phase can be stabilized by pressure and is actually found to have m axim al T<sub>c</sub>. Near x=0.125 for the Ba system, pressure destroys the LTT phase, yet superconductivity is still strongly suppressed.

Understanding this series of puzzling results m ay help to unravel the mystery behind high tem perature superconductivity. An obvious rst step in this direction is to understand the e ect these various structural distortions have on the electronic structure. Of course, m any band structure calculations have been performed on these systems in the past<sup>2</sup>. A recent calculation by P ickett et al<sup>3</sup> for the LTT phase revealed a strong suppression in the density of states (DOS) near the Ferm i energy ( $E_F$ ), which they then connected to the suppressed superconductivity of this phase. Because of this intriguing result, and the various additional experimental phenomena mentioned above, we decided to perform a series of band calculations for the various phases, accurately calculate the DOS in the vicinity of  $E_F$ , and attempt to connect these results to the experimental observations.

We use the linearized mu n tin orbital method<sup>4</sup>, including combined correction terms. Three independent codes were employed as checks, one of which contains non-spherical

corrections to the potential inside them u n tins<sup>5</sup> (all three codes gave com parable results). The calculations presented in this paper are scalar relativistic, employ the Hedin-Lundqvist form for the exchange-correlation potential, and use two empty spheres per formula unit (located at the (1/2,0,1/4) points in HTT notation). Doping was simulated by reducing the Z value of the La site. Calculations were converged on a 90 k point mesh inside the irreducible wedge of the Brillouin zone. For the naliteration, eigenvalues for 180 k points for the HTT and LTO and 144 k points for the LTT phase were generated and the results were tusing a Fourier series spline analysis. The spline twas checked by plotting bands along various symmetry directions, and then used to generate a DOS based on a tetrahedral decom position of the zone (around 1.6 million tetrahedra were used).

The HTT calculation was done using the lattice parameters of C ox et al<sup>6</sup> for x= 0.1 Ba at 295 K. Four LTO calculations were carried out, one which used the results<sup>6</sup> for x= 0.1 Ba at 91 K, and three which used new results on the Sr system at 10 K for x values of 0.1, 0.15, and 0.2<sup>7</sup>. Two LTT calculations were performed, one which used the results<sup>6</sup> for x= 0.1 Ba at 15 K, and another based on the theoretical parameters of P ickett et al<sup>3</sup> obtained by m inim ization of the total energy<sup>8</sup>. The latter set of parameters has a tilt angle of the copper oxide octahedra about twice that of the form er.

Before moving to the main discussion on the DOS, we rst comment on the matter of rigid band behavior. This has been questioned based on the fact that the Cu ion would prefer to be close to a d<sup>9</sup> con guration, and thus rigid band behavior may not be observed since the states at  $E_F$  are a mixture of Cu d and O p states. Our own doping results, based on adjusting the Z value of the La nucleus, exhibit an intriguing behavior. W hile we indeed found rigid band behavior in the DOS, the charge density did not exhibit such behavior. In particular, the DOS has about 60% Cu d character, with the remainder mostly O p. But comparing charges at 0% doping and 10% doping, only about 20% of the change in charge came from the Cu d orbitals, with the remaining 80% coming from the La site. We

should note that the charge on the La site is alm ost all due to reanalysis of charge from the surrounding 0 sites since the LM TO m ethod uses overlapping spheres. Our speculation is that the change in potential on the La site due to the reduction of the Z value causes the charge analysis on that site to change in order to compenstate for the charge loss due to doping, thus largely preserving the d count on the Cu site. This occurs, how ever, in such a way that rigid band behavior is maintained in the DOS.

In Fig. 1, we show plots of the LTO and HTT DOS for the x=0.1 Ba calculation. The HTT results were generated assuming LTO symmetry so as to eliminate di erences due to using di erent Brillouin zones. As one can see, there are virtually no di erences in the curves. This has been further veried by plots of the Ferm i surface which show no detectable di erences between HTT and LTO (the "gaps" seen in the LTO Ferm i surface plots in the literature<sup>2</sup> are simply a zone-fold back e ect and have nothing to do with the orthorhom bic distortion).

We show plots of the LTO DOS for the x=0.1, x=0.15, and x=0.2 Sr calculations in Fig. 2. Again, there are virtually no di erences in the curves, indicating again that the orthorhom bic distortion has only a weak e ect on the DOS (we note that the orthorhom bic distortion increases as x decreases).

P lots of the LTT and HTT DOS for the x= 0.1 Ba calculation are presented in Fig. 3. The HTT results were generated assuming LTT symmetry so as to eliminate di erences due to the di ering B rillouin zones. The zero of energy was set at 12.5% doping, where the LTT phase is seen experimentally. Again, there are virtually no di erences in the DOS. This indicates that the suppression of  $T_c$  for the LTT phase is probably not connected with a density of states e ect.

In Fig. 4, we show plots of our LTT calculation for x=0.1 Ba versus a calculation done using the lattice parameters of the previous work of Pickett et al<sup>3</sup>. We note that

the octahedral tilt angle used in their work is about a factor of two larger than what we used based on the C ox et al param eters<sup>6</sup>. One can see that the van H ove peak is split with the P ickett et al<sup>3</sup> param eters (our D O S plot is very similar to theirs). The van H ove peak is also split with our choice of param eters, but the elect is too small to be noticeable in the D O S. This dill erence occurs because the splitting of the van H ove peak depends quadratically on the tilt angle<sup>8</sup>. The large splitting in the P ickett et al<sup>3</sup> case gives a notch in the D O S close to  $E_F$  which led them to suspect that this might be responsible for the suppressed superconductivity. Because of this strong dependence on tilt angle, it is of som e im portance for experimentalists to attem pt to accurately determ ine the octahedral tilt angle for the LTT structure.

We conclude this part by remarking that the LTO and LTT structural distortions have little e ect on the DOS, though large di erences are found for the LTT case with increased octahedral tilt angle. Moreover, in proved sam pling of the zone by using more calculated k points acts to sharpen the calculated van Hove singularity (thus, most published plots of the DOS underestimates the height of this peak). We should also remark that the LMTO calculations place the van Hove singularity at about 21–22% doping, whereas FLAPW calculations place this peak at about 17% doping<sup>2</sup>. We have found that LMTO calculations which do not include the combined correction terms place the van Hove peak at the sam e doping as the FLAPW calculations, indicating that the location of the peak is sensitive to details of the electronic structure calculation.

We now attempt to connect some of these observations with experiment. We start with the LTO! HTT transition induced by pressure<sup>1</sup>.  $T_c$  increases linearly with pressure, then saturates at this transition. The pressure dependence of the structural transition can be estimated from anomalies in the thermal expansion. To describe this, we employ a theory due to Bilbro and M dM illan<sup>9</sup>. This theory assumes that the superconducting pair potential is independent of pressure, and that the pressure dependence com es from a

competition between a DOS change caused by the structural distortion and the form ation of a superconducting gap. This involves solving two coupled mean eld equations involving the superconducting gap and the charge density wave gap (assumed to only occur over part of the Ferm i surface). At a pressure where the two transitions merge, the ratio of  $dT_s$ =dp to  $dT_c=dp$  (where  $T_s$  is the structural transition temperature,  $T_c$  the superconducting transition tem perature, and p the pressure) is equal to (N  $N_1$ )= $N_1$  (where N is the totalDOS, and N<sub>1</sub> is that part of the DOS rem oved by the structural distortion). The data for both x=0.17 and x=0.19 (where some information exists for estimating the pressure dependence of the structural transition) give values of  $dT_c=dp$  ' -5.75 K /kbar and  $dT_c=dp$ ' 0.15 K/kbar. Thus, N<sub>1</sub>=N ' 0.025, i.e., only 2.5% of the N ( $E_F$ ) value is a ected by the structural transition. Such a sm all num ber is within the error bars of the band calculations, and thus the data independently support our conclusion that the LTO distortion has a very weak e ect on the DOS. Moreover, this theory would also predict that for pressures where the structural transition is near (but larger than)  $T_{c}$ , one should see a saturation of the orthorhom bic distortion for  $T < T_c$ . This e ect should be observable by neutron scattering experim ents.

As for the LTO! LTT phase transition and the resultant suppression of superconductivity, our conclusion based on this work is that the density of states does not play an important role. This is consistent with the pressure data, which show that even when the LTT transition is gone, superconductivity is still suppressed. Recent data<sup>10</sup> indicate that m agnetic ordering occurs for this concentration range, and thus is the m ost likely reason for the T<sub>c</sub> suppression. Given that band structure calculations do not give rise to a m agnetic transition for stochiom entric La<sub>2</sub>C uO<sub>4</sub>, we do not expect to be able to describe this m agnetism. A shas been noted, the m agnetism m ay be due to a commensuration e lect at x=1/8. M ore theoretical work is certainly needed to address this interesting e lect.

In conclusion, we different extension of the structural distortions of doped  $L_{a}C \cup O_{4}$  on

the electronic density of states. This result is supported by som e experimental data on both the HTT! LTO and LTO! LTT transitions.

This work was supported by the National Science Foundation (DMR 91-20000) through the Science and Technology Center for Superconductivity. MRN was also supported by the U.S.D epartment of Energy, O ce of Basic Energy Sciences, under Contract No. W -31-109-ENG -38. MRN would like to acknow ledge the hospitality of the C avendish Laboratory, C am bridge University, where some of this work was performed (with additional support from the UK SERC and Trinity College, C am bridge). We thank Jim Jorgensen and Bernd Schuttler for calling our attention to this problem and suggesting these calculations. We also acknow ledge helpful conversations with D ale K celling, and with M ike C raw ford and D avid H inks concerning the experimental data. We are also indebted to W arren P ickett and R on C ohen for many correspondences concerning the LTT results.

## REFERENCES

- 1.N.Yam ada and M.Ido, Physica C 203, 240 (1992).
- 2.W E.Pickett, Rev.M od.Phys. 61, 433 (1989).
- 3.W E.Pickett, R.E.Cohen, and H.K rakauer, Phys. Rev. Lett. 67, 228 (1991).
- 4.0 K.Andersen, Phys.Rev.B 12, 3060 (1975).
- 5.M. Methfessel, C.O. Rodriguez, and O.K. Andersen, Phys. Rev. B 40, 2009 (1989).
- 6.D E.Cox, P.Zolliker, JD.Axe, A H M oudden, A R.M oodenbaugh, and Y.Xu, M at. Res.Soc.Symp.Proc.156, 141 (1989).
- 7.D avid H inks, private com m unication.
- 8. The authors thank W arren Pickett and R on C ohen for their lattice parameters and the observation about the quadratic dependence of the van H ove splitting on tilt angle.
- 9.G.Bibro and W L.M dM illan, Phys.Rev.B 14, 1887 (1976).
- 10. I.W atanabe, K.Kawano, K.Kumagi, K.Nishiyama, and K.Nagamine, J.Phys.Soc. Japan 61, 3058 (1992).

- Density of states (per form ula unit) for the HTT and LTO x= 0.1 Ba cases. The zero of energy is at x= 0.1
- 2. Density of states (per form ula unit) for the LTO x= 0.1, 0.15, and 0.2 Sr cases. The zero of energy is at x= 0.1
- 3. Density of states (per form ula unit) for the HTT and LTT x= 0.1 Ba cases. The zero of energy is at x= 0.125
- 4. Density of states (per formula unit) for the LTT x=0.1 Ba case (C ox) and the LTT case with the P ickett et al lattice parm aters (P ic). The zero of energy is at x=0.125